

DB3X209K0L

Schottky Barrier Diode DB3X209K0L

Silicon epitaxial planar type

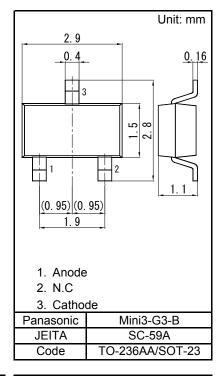
For high frequency rectification

- Features
- Low forward voltage VF
- Short reverse recovery time trr
- Halogen-free / RoHS compliant (EU RoHS / UL-94 V-0 / MSL:Level 1 compliant)

Marking Symbol:4S

Packaging

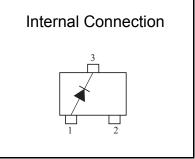
Embossed type (Thermo-compression sealing) : 3 000 pcs / reel (standard)



■ Absolute Maximum Ratings Ta = 25 °C

| Parameter | Symbol | Rating | Unit | | | |
|--|--------|-------------|------|--|--|--|
| Reverse voltage | VR | 20 | V | | | |
| Repctitive peak reverse voltage | VRRM | 20 | V | | | |
| Forward current (Average) | IF(AV) | 500 | mA | | | |
| Non-repetitive peak forward surge current *1 | IFSM | 3 | А | | | |
| Junction temperature | Tj | 125 | °C | | | |
| Operating ambient temperature | Topr | -40 to +85 | °C | | | |
| Storage temperature | Tstg | -55 to +125 | С° | | | |
| | | | | | | |

Note: *1 50 Hz sine wave 1 cycle (Non-repetitive peak current)



Panasonic

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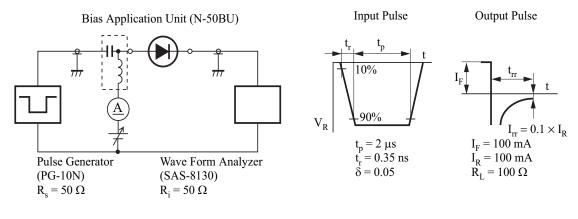
| Electrical Characteristics | Ta = 25 °C ± 3 °C |
|----------------------------|-------------------|
| | |

| Parameter | Symbol | Conditions | Min | Тур | Max | Unit |
|--------------------------|--------|---------------------------|-----|-----|-----|------|
| Forward voltage | VF1 | IF = 10 mA | | | 0.3 | V |
| | VF2 | IF = 500 mA | | | 0.5 | V |
| Reverse current | IR | VR = 10 V | | | 30 | μA |
| Terminal capacitance | Ct | VR = 10 V, f = 1 MHz | | 7 | | pF |
| Reverse recovery time *1 | trr | IF = IR = 100 mA, | | 2.4 | | ns |
| | ul | Irr = 0.1× IR, RL = 100 Ω | | | | |

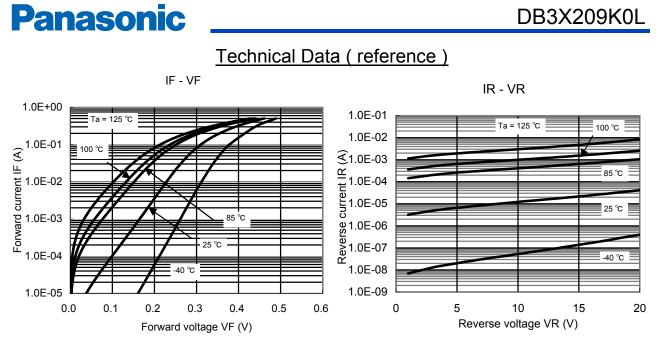
Note: 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7031 measuring methods for diodes.

2. This product is sensitive to electric shock (static electricity, etc.). Due attention must be paid on the charge of a human body and the leakage of current from the operating equipment.

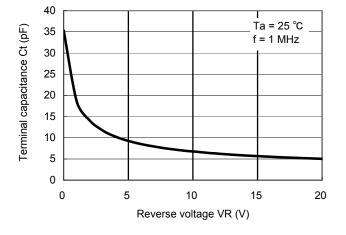
- 3. Absolute frequency of input and output is 400 MHz.
- 4. *1 : trr measurement circuit



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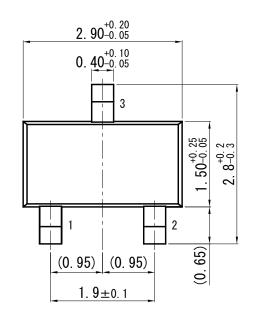
Doc No. TT4-EA-12404 Revision. 2

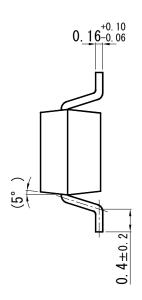


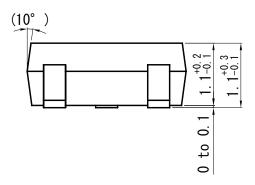
Mini3-G3-B

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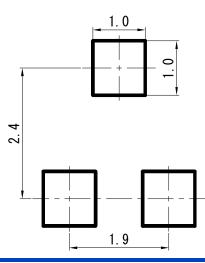
Unit: mm







■ Land Pattern (Reference) (Unit: mm)



Established : 2010-02-26 Revised : 2013-12-13

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